

Dual surface mount switching diode

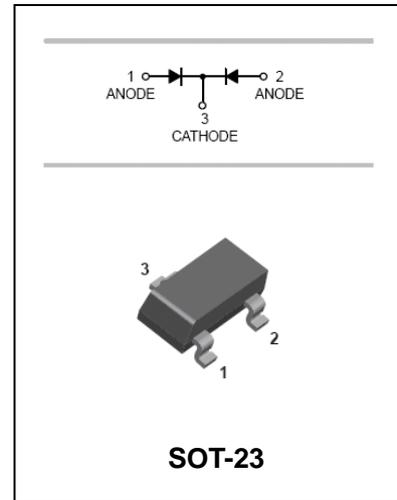
**1SS337**

**FEATURES**

- Low forward voltage:  $V_{F(3)}=0.88V(\text{typ})$ .
- Fast reverse recovery time:  $t_{rr}=6\text{ns}(\text{typ})$ .
- Small total capacitance:  $C_T=1.6\text{pF}(\text{typ})$ .



Lead-free



**APPLICATIONS**

- Ultra high speed switching application.

**ORDERING INFORMATION**

Type No.	Marking	Package Code
1SS337	J9	SOT-23

**MAXIMUM RATING @  $T_a=25^\circ\text{C}$  unless otherwise specified**

Parameter	Symbol	Limits	Unit
Maximum (peak) reverse voltage	$V_{RM}$	85	V
DC Reverse Voltage	$V_R$	80	V
Average rectified output current	$I_O$	200	mA
Forward Surge Current @ $t=10\text{ms}$	$I_{FSM}$	6	A
Power Dissipation	$P_d$	150	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

**ELECTRICAL CHARACTERISTICS @  $T_a=25^\circ\text{C}$  unless otherwise specified**

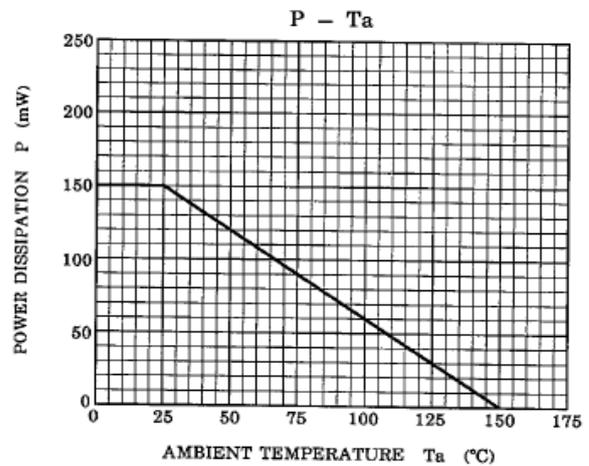
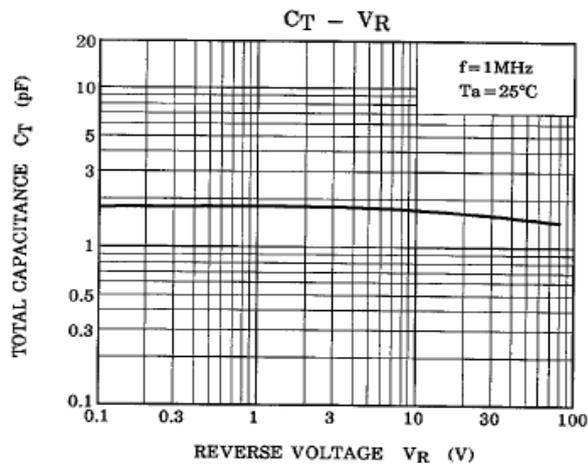
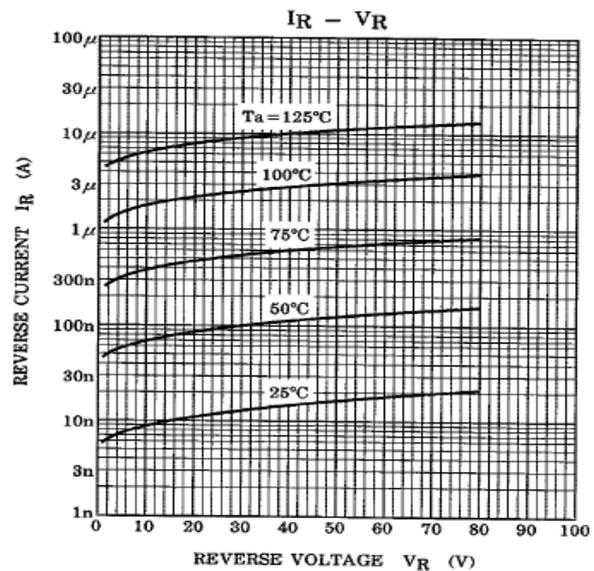
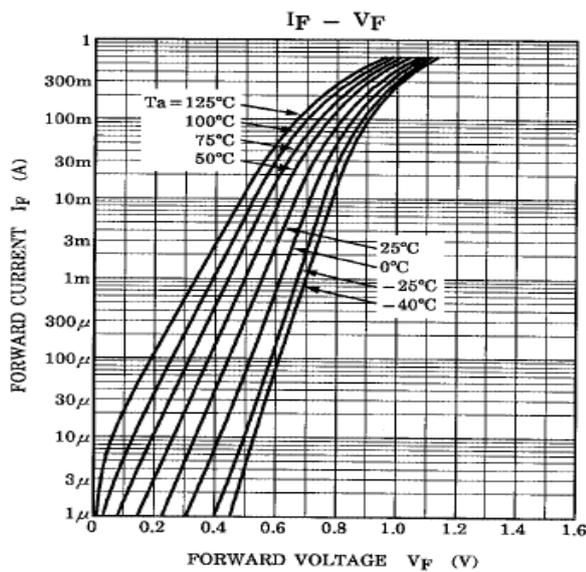


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Parameter	Symbol	Test conditions	MIN	Typ	MAX	UNIT
Reverse breakdown voltage	$V_{(BR)R}$	$I_R = 100\mu A$	80	-	-	V
Reverse voltage leakage current	$I_R$	$V_R = 30V$ $V_R = 80V$	-	-	0.25 0.50	$\mu A$
Forward voltage	$V_F$	$I_F = 10mA$ $I_F = 100mA$ $I_F = 200mA$	-	0.66 0.80 0.88	-	V
Diode capacitance	$C_T$	$V_R = 0V, f = 1MHz$	-	1.6	-	pF
Reverse recovery time	$t_{rr}$	$I_F = I_R = 30mA, I_R = 1mA$ $V_R = 5V, R_L = 100\Omega$	-	6	20	ns

TYPICAL CHARACTERISTICS @  $T_a = 25^\circ C$  unless otherwise specified



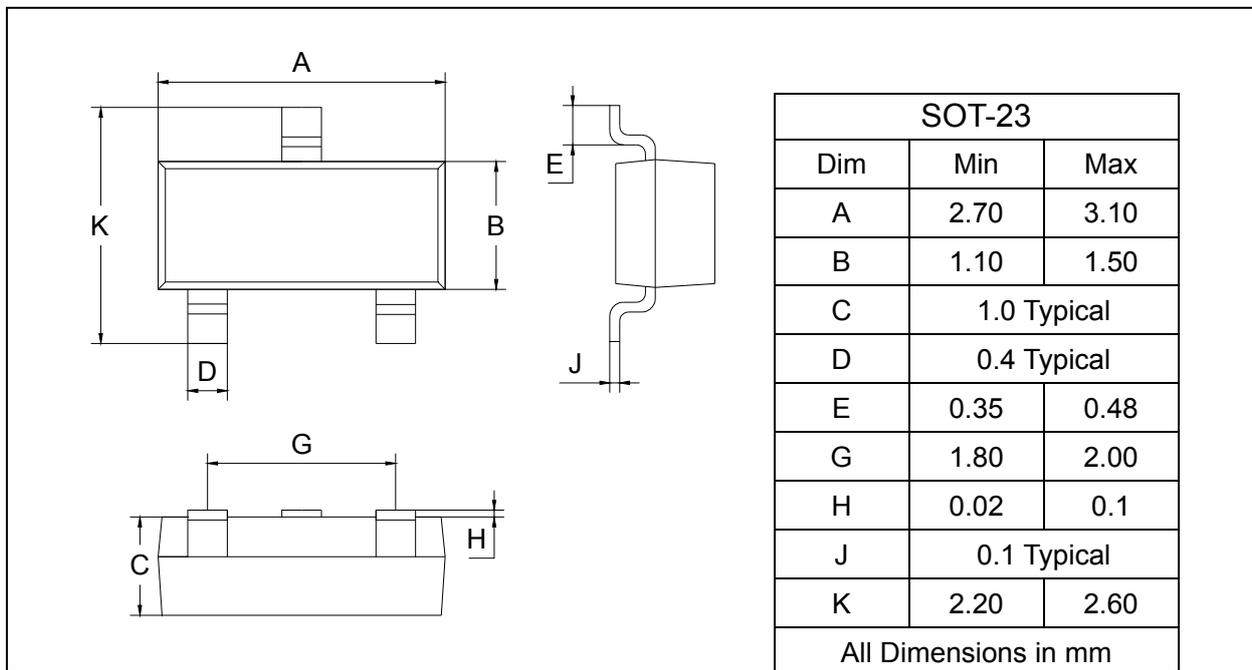
PACKAGE OUTLINE

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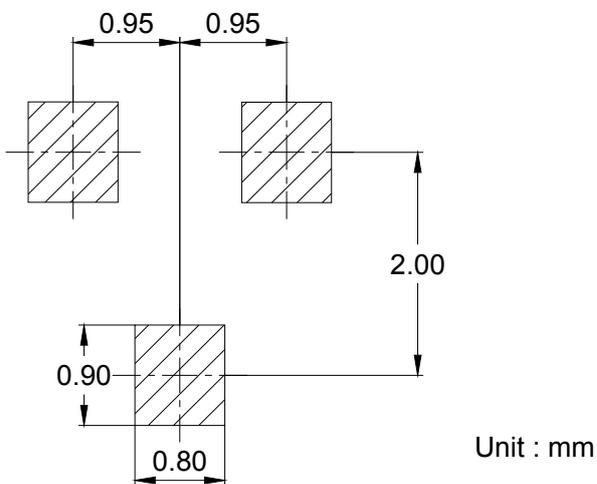
**1SS337**

Plastic surface mounted package

SOT-23



**SOLDERING FOOTPRINT**



**PACKAGE INFORMATION**

Device	Package	Shipping
1SS337	SOT-23	3000/Tape&Reel